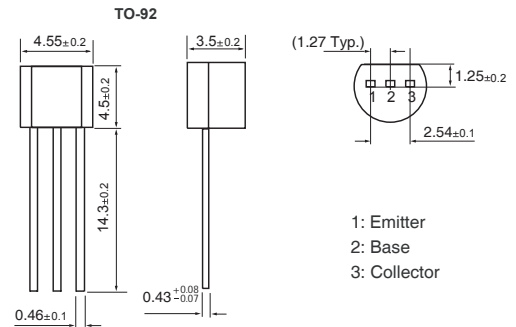


**FEATURES**

- Complimentary to S8550
- Collector Current:  $I_C = 0.5\text{ A}$


**ABSOLUTE MAXIMUM RATINGS at  $T_a = 25^\circ\text{C}$** 

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	$V_{CBO}$	40	V
Collector to Emitter Voltage	$V_{CEO}$	25	V
Emitter to Base Voltage	$V_{EBO}$	5	V
Collector Current	$I_C$	500	mA
Total Power Dissipation	$P_D$	625	mW
Junction, Storage Temperature	$T_J, T_{STG}$	+150, -55 ~ +150	$^\circ\text{C}$

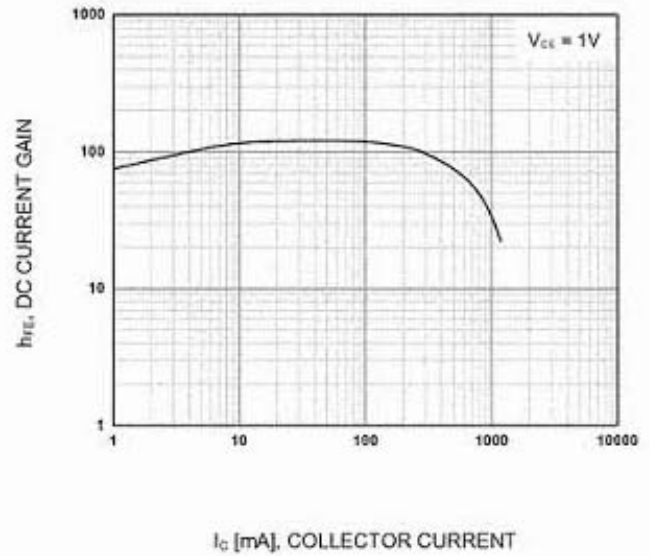
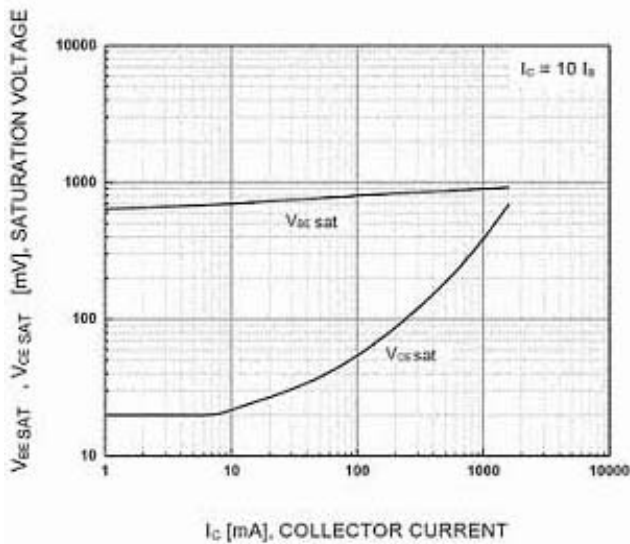
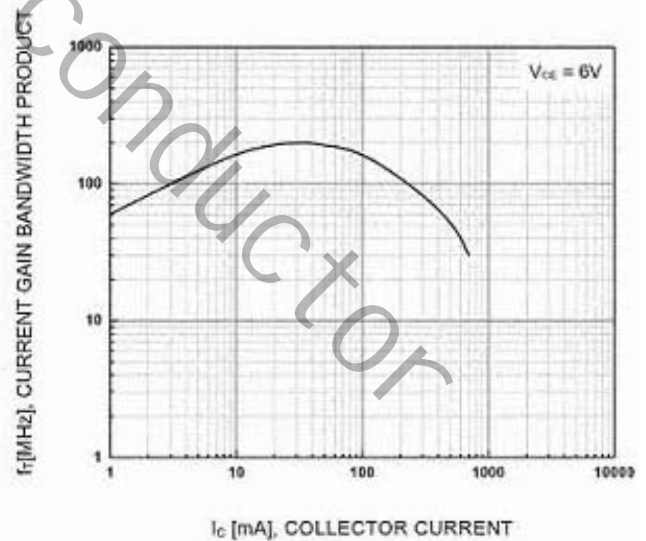
**ELECTRICAL CHARACTERISTICS ( $T_{AMB} = 25^\circ\text{C}$  unless otherwise specified)**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Collector-base Breakdown Voltage	$V_{(BR)CBO}$	40	-	-	V	$I_C = 100\ \mu\text{A}, I_E = 0$
Collector-emitter Breakdown Voltage	$V_{(BR)CEO}$	25	-	-	V	$I_C = 0.1\ \text{mA}, I_B = 0$
Emitter-base Breakdown Voltage	$V_{(BR)EBO}$	5	-	-	V	$I_E = 100\ \mu\text{A}, I_C = 0$
Collector Cut-off Current	$I_{CBO}$	-	-	0.1	$\mu\text{A}$	$V_{CB} = 40\ \text{V}, I_E = 0$
Collector Cut-off Current	$I_{CEO}$	-	-	0.1	$\mu\text{A}$	$V_{CE} = 20\ \text{V}, I_B = 0$
Emitter Cut-off Current	$I_{EBO}$	-	-	0.1	$\mu\text{A}$	$V_{EB} = 5\ \text{V}, I_C = 0$
DC Current Gain	$h_{FE(1)}$	85	-	400		$V_{CE} = 1\ \text{V}, I_C = 50\ \text{mA}$
	$h_{FE(2)}$	50	-	-		$V_{CE} = 1\ \text{V}, I_C = 500\ \text{mA}$
Collector-emitter Saturation Voltage	$V_{CE(sat)}$	-	-	0.6	V	$I_C = 500\ \text{mA}, I_B = 50\ \text{mA}$
Base-emitter Saturation Voltage	$V_{BE(sat)}$	-	-	1.2	V	$I_C = 500\ \text{mA}, I_B = 50\ \text{mA}$
Transition Frequency	$f_T$	150	-	-	MHz	$V_{CE} = 6\ \text{V}, I_C = 20\ \text{mA}, f = 30\ \text{MHz}$

**CLASSIFICATION OF  $h_{FE}$** 

Rank	B	C	D
Range	85 - 160	120 - 200	160 - 300

**CHARACTERISTIC CURVES**
**S8050**

**Static Characteristic**

**DC current Gain**

**Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage**

**Current Gain Bandwidth Product**

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